Octal Bus Buffer

Inverting

The MC74VHC540 is an advanced high speed CMOS inverting octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The MC74VHC540 features inputs and outputs on opposite sides of the package and two AND-ed active-low output enables. When either $\overline{\text{OE1}}$ or $\overline{\text{OE2}}$ are high, the terminal outputs are in the high impedance state.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

Features

- High Speed: $t_{PD} = 3.7 \text{ ns}$ (Typ) at $V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 4.0 \mu A$ (Max) at $T_A = 25^{\circ}C$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2.0 V to 5.5 V Operating Range
- Low Noise: V_{OLP} = 1.2 V (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: HBM > 2000 V; Machine Model > 200 V
- Chip Complexity: 124 FETs or 31 Equivalent Gates
- These Devices are Pb-Free and are RoHS Compliant

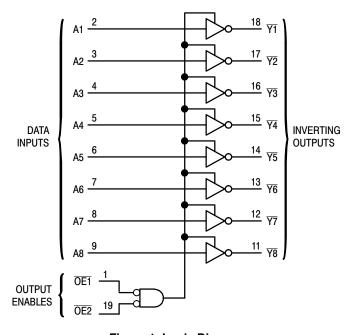


Figure 1. Logic Diagram



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MARKING DIAGRAMS









A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year

YY, Y = Year WW, W = Work Week G or ■ = Pb–Free Package

PIN ASSIGNMENT

| OE1 | 1● | 20 |] v _{cc} |
|-------|----|----|-------------------|
| A1 [| 2 | 19 |] OE2 |
| A2 [| 3 | 18 |] <u>Y1</u> |
| A3 [| 4 | 17 |] <u>Y2</u> |
| A4 [| 5 | 16 |] Y 3 |
| A5 [| 6 | 15 |] <u>Y4</u> |
| A6 [| 7 | 14 |] <u>Y5</u> |
| A7 [| 8 | 13 |] <u>∀6</u> |
| A8 [| 9 | 12 |] Y 7 |
| GND [| 10 | 11 |] <u>78</u> |
| | | | - |

FUNCTION TABLE

| | Inputs | Output V | |
|-----|--------|----------|----------|
| OE1 | OE2 | Α | Output ₹ |
| L | L | L | Н |
| L | L | Н | L |
| H | X | Х | Z |
| X | Н | X | Z |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS*

| Symbol | Parameter | r | Value | Unit |
|------------------|---|----------------------------------|--------------------------------|------|
| V _{CC} | DC Supply Voltage | | - 0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage | | - 0.5 to + 7.0 | V |
| V _{out} | DC Output Voltage | | - 0.5 to V _{CC} + 0.5 | V |
| I _{IK} | Input Diode Current | | - 20 | mA |
| I _{OK} | Output Diode Current | | ± 20 | mA |
| I _{out} | DC Output Current, per Pin | | ± 25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GN | ID Pins | ± 75 | mA |
| P _D | Power Dissipation in Still Air, | SOIC Packages† TSSOP Package† | 500 450 | mW |
| T _{stg} | Storage Temperature | | - 65 to + 150 | °C |

^{*} Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

†Derating — SOIC Packages: – 7 mW/°C from 65° to 125°C TSSOP Package: – 6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | | Max | Unit |
|---------------------------------|--|--|----------|-----------|------|
| V _{CC} | DC Supply Voltage | 2.0 | 5.5 | V | |
| V _{in} | DC Input Voltage | 0 | 5.5 | V | |
| V _{out} | DC Output Voltage | 0 | V_{CC} | V | |
| T _A | Operating Temperature, All Package Types | | | + 125 | °C |
| t _r , t _f | · | $V_{CC} = 3.3V \pm 0.3V$ $V_{CC} = 5.0V \pm 0.5V$ | 0 | 100 20 | ns/V |

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | T _A = 25°C | | ; | T _A = - 55 | to 125°C | |
|-----------------|--------------------------------------|--|----------------------|-------------------------------|-------------------|-------------------------------|-------------------------------|-------------------------------|------|
| Symbol | Parameter | Test Conditions | V | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | Minimum High-Level Input Voltage | | 2.0 3.0 to 5.5 | 1.50 V _{CC} x 0.7 | | | 1.50 V _{CC} x 0.7 | | ٧ |
| V _{IL} | Maximum Low-Level Input Voltage | | 2.0 3.0 to 5.5 | | | 0.50 V _{CC} x 0.3 | | 0.50 V _{CC} x 0.3 | ٧ |
| V _{OH} | Minimum High-Level Output Voltage | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$ | 2.0 3.0 4.5 | 1.9 2.9 4.4 | 2.0 3.0 4.5 | | 1.9 2.9 4.4 | | ٧ |
| | | $V_{in} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -4mA \\ I_{OH} = -8mA$ | 3.0 4.5 | 2.58 3.94 | | | 2.48 3.80 | | |
| V _{OL} | Maximum Low-Level Output Voltage | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu A$ | 2.0 3.0 4.5 | | 0.0 0.0 0.0 | 0.1 0.1 0.1 | | 0.1 0.1 0.1 | ٧ |
| | | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4mA$ $I_{OL} = 8mA$ | 3.0 4.5 | | | 0.36 0.36 | | 0.44 0.44 | |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC} .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | T _A = 25°C | | T _A = - 55 to 125°C | | | |
|-----------------|--|---|-----------------|-----------------------|-----|--------------------------------|-----|-------|------|
| Symbol | Parameter | Test Conditions | v | Min | Тур | Max | Min | Max | Unit |
| l _{in} | Maximum Input Leakage Current | V _{in} = 5.5V or GND | 0 to 5.5 | | | ± 0.1 | | ± 1.0 | μА |
| l _{OZ} | Maximum Three-State Leakage Current | $V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$ | 5.5 | | | ± 0.25 | | ± 2.5 | μА |
| Icc | Maximum Quiescent Supply Current | V _{in} = V _{CC} or GND | 5.5 | | | 4.0 | | 40.0 | μА |

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ns}$)

| | | | | | T _A = 25°C | | T _A = - 55 | to 125°C | |
|--|---|--|--|-----|-----------------------|--------------|-----------------------|--------------|------|
| Symbol | Parameter | Test Condi | tions | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, A to \(\overline{Y} \) | $V_{CC} = 3.3 \pm 0.3 V$ | $C_L = 15pF$ $C_L = 50pF$ | | 4.8 7.3 | 7.0 10.5 | 1.0 1.0 | 8.5 12.0 | ns |
| | (Figures 1 and 3) | $V_{CC} = 5.0 \pm 0.5 V$ | $C_L = 15pF$ $C_L = 50pF$ | | 3.7 5.2 | 5.0 7.0 | 1.0 1.0 | 6.0 8.0 | |
| t _{PZL} , t _{PZH} | Output Enable Time, OEn to Y | $\begin{aligned} V_{CC} &= 3.3 \pm 0.3 V \\ R_L &= 1 k \Omega \end{aligned}$ | C _L = 15pF C _L = 50pF | | 6.8 9.3 | 10.5 14.0 | 1.0 1.0 | 12.5 16.0 | ns |
| | (Figures 2 and 4) | $V_{CC} = 5.0 \pm 0.5V$ $R_L = 1k\Omega$ | C _L = 15pF C _L = 50pF | | 4.7 6.2 | 7.2 9.2 | 1.0 1.0 | 8.5 10.5 | |
| t _{PLZ} , t _{PHZ} | Output Disable Time, OEn to Y | $\begin{aligned} V_{CC} &= 3.3 \pm 0.3 V \\ R_L &= 1 k \Omega \end{aligned}$ | C _L = 50pF | | 11.2 | 15.4 | 1.0 | 17.5 | ns |
| | (Figures 2 and 4) | $V_{CC} = 5.0 \pm 0.5V$ $R_L = 1 k\Omega$ | C _L = 50pF | | 6.0 | 8.8 | 1.0 | 10.0 | |
| t _{OSLH} , t _{OSHL} | Output to Output Skew | V _{CC} = 3.3 ± 0.3V (Note 1) | C _L = 50pF | | | 1.5 | | | ns |
| | | V _{CC} = 5.0 ± 0.5V (Note 1) | C _L = 50pF | | | 1.0 | | | ns |
| C _{in} | Maximum Input Capacitance | | | | 4 | 10 | | 10 | pF |
| C _{out} | Maximum Three-State Output Capacitance (Output in High Impedance State) | | | | 6 | | | | pF |

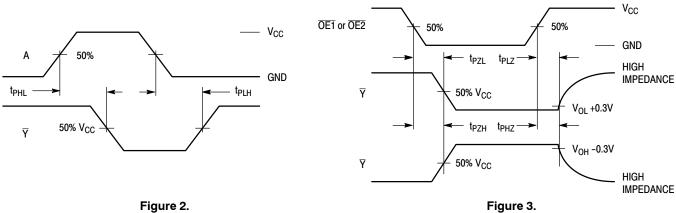
| | | Typical @ 25°C, V _{CC} = 5.0V | |
|----------|--|--|----|
| C_{PD} | Power Dissipation Capacitance (Note 2) | 17 | pF |

NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ns}$, $C_L = 50 \text{pF}$, $V_{CC} = 5.0 \text{V}$)

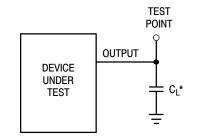
| | | T _A = 25°C | | |
|------------------|--|-----------------------|-------|------|
| Symbol | Parameter | Тур | Max | Unit |
| V _{OLP} | Quiet Output Maximum Dynamic V _{OL} | 0.9 | 1.2 | V |
| V _{OLV} | Quiet Output Minimum Dynamic V _{OL} | - 0.9 | - 1.2 | V |
| V _{IHD} | Minimum High Level Dynamic Input Voltage | | 3.5 | V |
| V_{ILD} | Maximum Low Level Dynamic Input Voltage | | 1.5 | V |

Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.
 C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/8 (per bit). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

SWITCHING WAVEFORMS

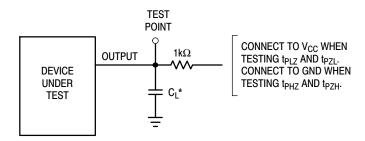


TEST CIRCUITS



*Includes all probe and jig capacitance

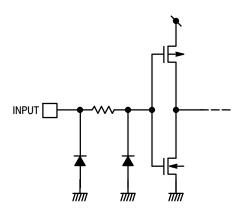
Figure 4.



*Includes all probe and jig capacitance

Figure 5.

INPUT EQUIVALENT CIRCUIT



ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|-----------------------|--------------------------|
| MC74VHC540DWR2G | SOIC-20 (Pb-Free) | 1000 Units / Tape & Reel |
| MC74VHC540DTR2G | TSSOP-20 (Pb-Free) | 2500 Units / Tape & Reel |

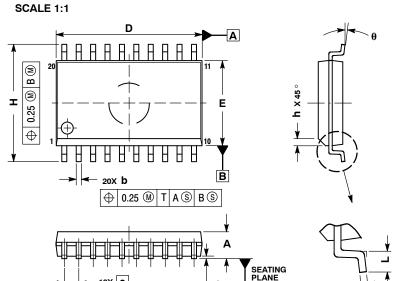
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.





SOIC-20 WB CASE 751D-05 **ISSUE H**

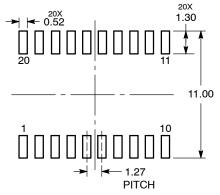
DATE 22 APR 2015



- DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

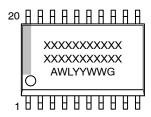
| | MILLIMETERS | | | |
|-----|-------------|-------|--|--|
| DIM | MIN | MAX | | |
| Α | 2.35 | 2.65 | | |
| A1 | 0.10 | 0.25 | | |
| b | 0.35 | 0.49 | | |
| С | 0.23 | 0.32 | | |
| D | 12.65 | 12.95 | | |
| E | 7.40 | 7.60 | | |
| е | 1.27 | BSC | | |
| Н | 10.05 | 10.55 | | |
| h | 0.25 | 0.75 | | |
| L | 0.50 | 0.90 | | |
| θ | 0 ° | 7 ° | | |

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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| DESCRIPTION: | SOIC-20 WB | | PAGE 1 OF 1 | | |

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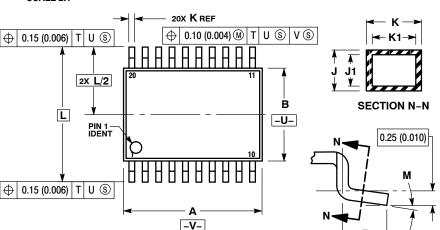
^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

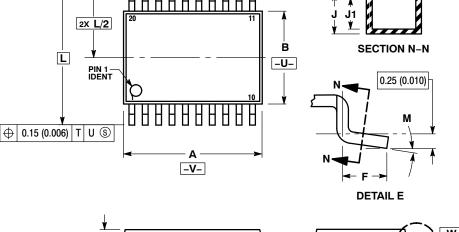
0.100 (0.004) -T- SEATING

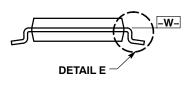


TSSOP-20 WB CASE 948E ISSUE D

DATE 17 FEB 2016







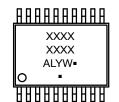
NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
- (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-

| | MILLIN | IETERS | INCHES | |
|-----|----------|--------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 6.40 | 6.60 | 0.252 | 0.260 |
| В | 4.30 | 4.50 | 0.169 | 0.177 |
| С | | 1.20 | | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| Н | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| М | 0° | 8° | 0° | 8° |

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| SOLDERING | FOOTPRINT |
|--------------|-------------------------|
| 7. | 06 ─── |
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| ₁ | ———— PITCH |
| 16X | |
| 1.26 | DIMENSIONS: MILLIMETERS |

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|------------------|-------------|---|-------------|
| DESCRIPTION: | TSSOP-20 WB | • | PAGE 1 OF 1 |

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16X

0.36

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